
Session Title:	58. Oxide TFT II
Date:	Aug. 26, 2016 (Friday)
Time:	10:30~11:35
Room	Room B (Halla B)
Session Chair	Dr. Hui Huang (Univ. of chinese academy of sciences, China)

B58-1

10:30~10:55

[Invited] Implantable Organic Electronics for Pathologies of the Central Nervous System

Michele Di Lauro, Marcellp Berto, Carlo Augusto Bortolotti (Univ. of Modena and Reggio Emilia, Italy), Mauro Murgia (CNR-ISMN, Italy), Michele Zoli (Univ. of Modena and Reggio Emilia, Italy), and Fabio Biscarini (Univ. of Modena and Reggio Emilia, Italy)

B58-2

10:55~11:20

[Invited] Oxide Thin-Film Transistors with In Situ Anodized Passivation Layers

Shengdong Zhang, Yang Shao, Xiang Xiao, Yong Le, Letao Zhang, and Xiaoliang Zhou (Peking Univ., China)

B58-3

11:20~11:35

High Performance Siloxane Hybrid Polymer Gate Insulator for Amorphous InGaZnO Thin-Film Transistors.

Chaiyanan Kulchaisit, Yasuaki Ishikawa, Mami N. Fujii, Haruka Yamazaki, Juan Paolo Bermundo, and Yukiharu Uraoka (NAIST, Japan)